

300mA Low Quiescent Current Low-Dropout Linear Regulator

Features

- Input voltage range: 1.2V to 5.5V
- Fixed outputs of 1.2V, 1.8V, 2.8V, 3.0V, 3.3V
- Rated output current: 300mA
- Quiescent current: typical 2 μ A
- Typical 0.1 μ A shutdown current
- Typical 320mV dropout voltage ($I_{OUT}=300mA$, 1.8V output)
- Power supply rejection ratio: typical 75dB ($I_{OUT}=30mA$, freq=1kHz, 1.8V output)
- Noise: typical 60 μ Vrms ($I_{OUT}=30mA$, BW=10Hz to 100kHz, 1.8V output)
- Built-in output short protection: typical 300mA when output short to ground
- DFN 1mmX1mmX0.37mm-4L package

General Description

AW37104YXXX is a low quiescent current low dropout voltage regulator featuring low ON resistance, high PSRR, low Noise, good load/line transient response and smooth soft-start.

AW37104YXXX integrates current limit, short circuit protection, thermal shutdown, sufficiently protecting IC from being damaged.

AW37104YXXX is designed to work with a 1 μ F or more input ceramic capacitor and a 1 μ F or more output ceramic capacitor. The low quiescent current make AW37104YXXX very suitable for battery application with long service life. Tiny package makes high density mounting of the IC on boards possible.

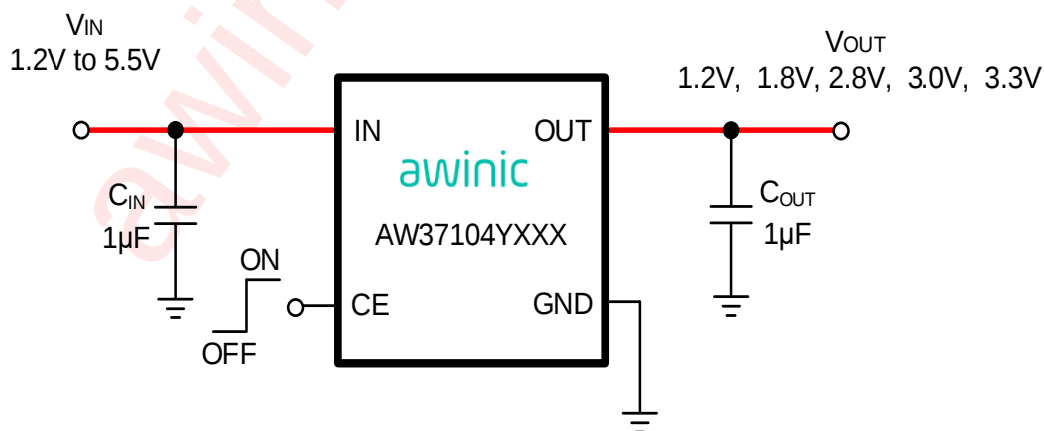
Applications

Battery-powered equipment

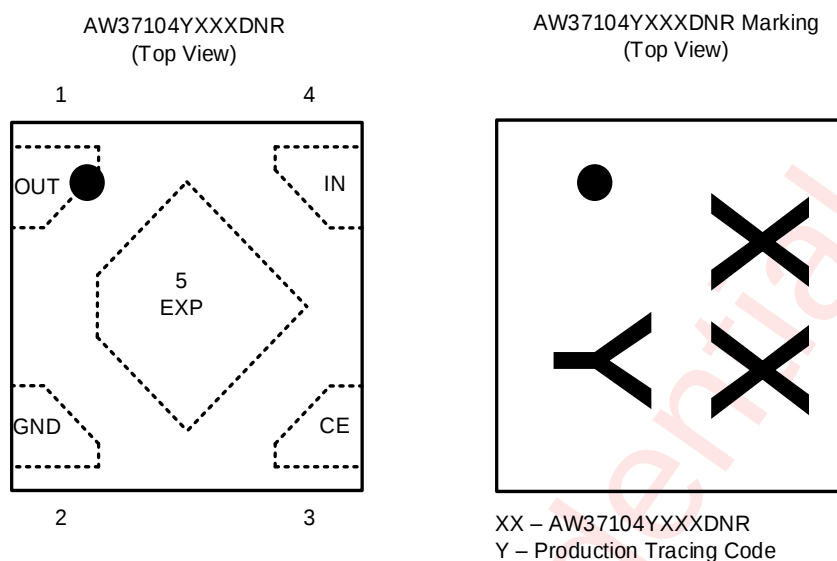
Smart phone

Wearables electronics

Typical Application Circuit



Pin Configuration And Top Mark



Pin Definition

No.	NAME	DESCRIPTION
1	OUT	Regulated output voltage pin. Put a 1 μ F or more ceramic capacitor at the output pin.
2	GND	Ground.
3	CE	Chip enable pin. Built-in 30nA pull-down current. (High Active)
4	IN	Input supply pin. Put a 1 μ F or more bypass capacitor at the power supply.
5	EXP	Expose pad should be tied to ground plane for better power dissipation.

Name Rule

AW37104 Y XXX ZZZ

Package

DNR: DFN 1mmX1mmX0.37mm-4L

Output Voltage

E.g.
180: Output Voltage 1.8V

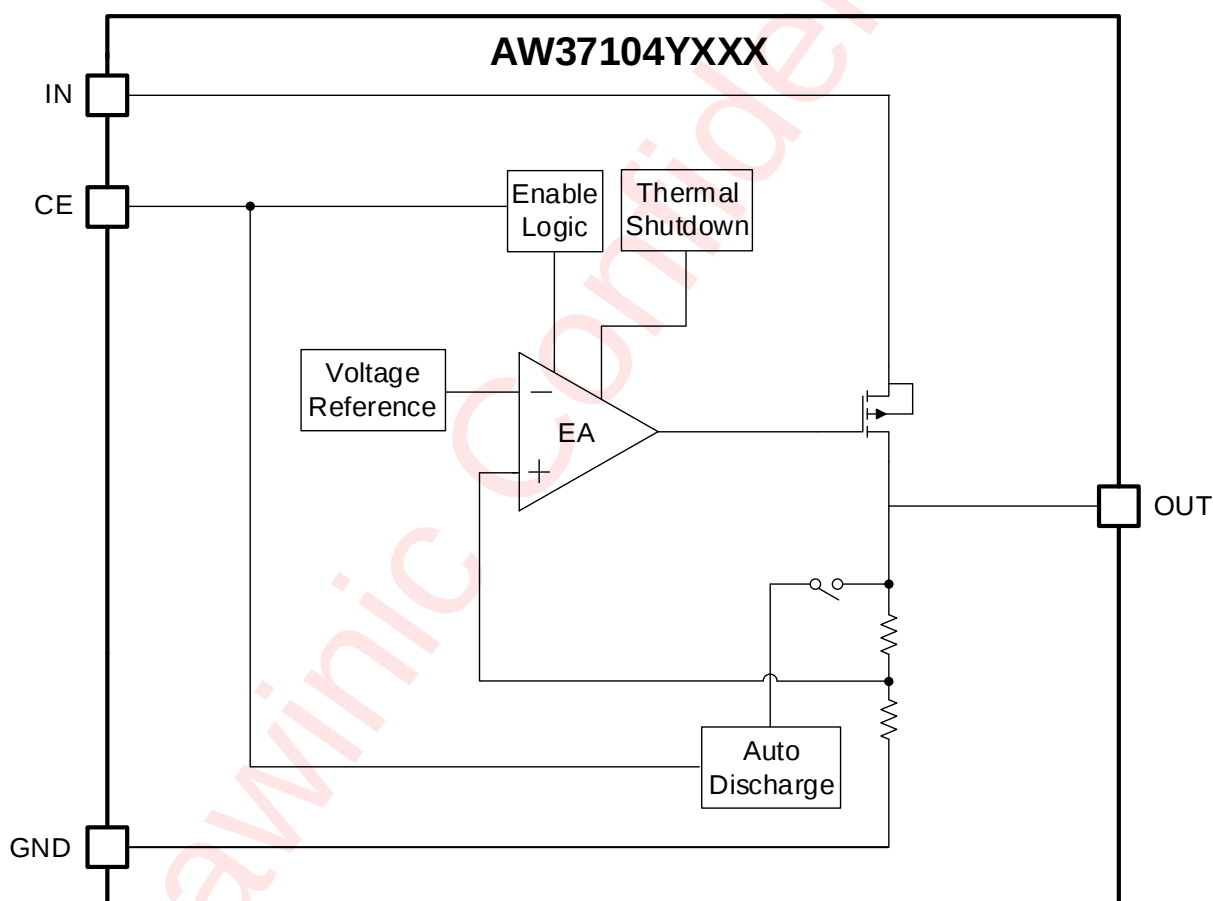
Auto-discharge Function

D: Available
B: Not available

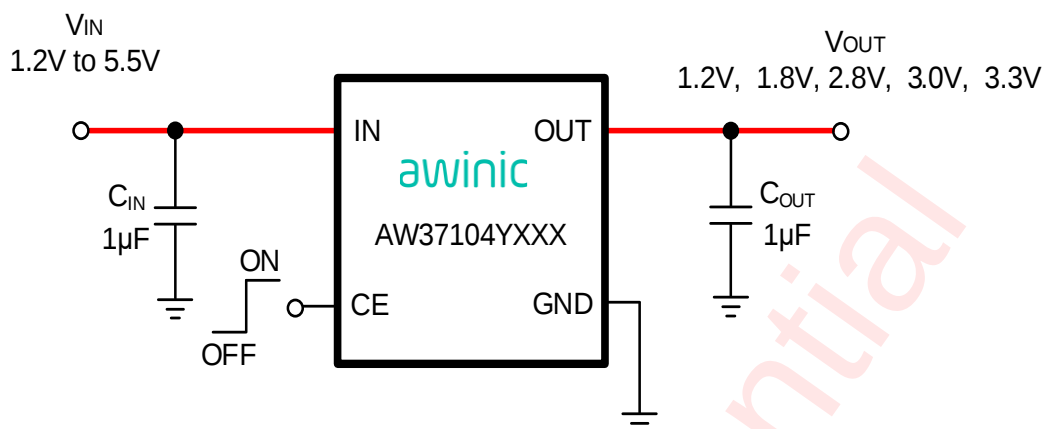
Device Comparison Table

Part Number	$V_{OUT(SET)}$	Rated Current	CE Active	Auto Discharge
AW37104D120DNR	1.2V	300mA	High	YES
AW37104D180DNR	1.8V	300mA	High	YES
AW37104D280DNR	2.8V	300mA	High	YES
AW37104D300DNR	3.0V	300mA	High	YES
AW37104D330DNR	3.3V	300mA	High	YES

Functional Block Diagram



Typical Application Circuits



Notice for typical application circuits:

Capacitance of C_{IN} and C_{OUT} should be $1\mu F$ or more.

A ceramic capacitor has different temperature characteristics and bias dependencies depending on the size, manufacturer or part number of a capacitor. Careful evaluation is required. The effective capacitance of C_{OUT} should be greater than $0.7\mu F$ over the full range of operating conditions.

Ordering Information

Part Number	Temperature	Package	Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW37104D120DNR	-40°C~85°C	DFN 1mmX1mm-4L	8J	MSL1	ROHS+HF	9000 units/ Tape and Reel
AW37104D180DNR	-40°C~85°C	DFN 1mmX1mm-4L	ZJ	MSL1	ROHS+HF	9000 units/ Tape and Reel
AW37104D280DNR	-40°C~85°C	DFN 1mmX1mm-4L	8E	MSL1	ROHS+HF	9000 units/ Tape and Reel
AW37104D300DNR	-40°C~85°C	DFN 1mmX1mm-4L	4T	MSL1	ROHS+HF	9000 units/ Tape and Reel
AW37104D330DNR	-40°C~85°C	DFN 1mmX1mm-4L	5B	MSL1	ROHS+HF	9000 units/ Tape and Reel

Absolute Maximum Ratings^(NOTE1)

PARAMETERS	RANGE
Input voltage range	-0.3V to 6.5V
Enable control voltage range	-0.3V to 6.5V
Output voltage range	-0.3V to VIN+0.3V, max. 6.5V
Maximum operating junction temperature T _{JMAX}	150°C
Recommended operating junction temperature T _{JREC}	-40°C to 125°C
Operating free-air temperature range	-40°C to 85°C
Storage temperature T _{STG}	-65°C to 150°C
Lead temperature (soldering 10 seconds)	260°C
Junction-to-ambient thermal resistance θ_{JA} ^(NOTE2)	232°C/W
ESD	
HBM (Human body model) ^(NOTE3)	±2kV
CDM(Charged device model) ^(NOTE4)	±1.5kV
Latch-Up	
Latch-Up ^(NOTE5)	+IT: 200mA - IT: -200mA

NOTE1: Conditions out of those ranges listed in "absolute maximum ratings" may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should within the ranges listed in "recommended operating conditions". Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

NOTE2: Thermal resistance from junction to ambient follows JEDEC 2S2P standards, and is highly dependent on PCB layout.

NOTE3: All pins. Test Condition: ESDA/JEDEC JS-001-2017.

NOTE4: All pins. Test Condition: ESDA/JEDEC JS-002-2018.

NOTE5: Test Condition: JESD78E.

Electrical Characteristics

$V_{IN}=V_{OUT(SET)}+1V$, $V_{CE}>1V$, $I_{OUT}=1mA$, $C_{IN}=C_{OUT}=1\mu F$, $T_A=25^{\circ}C$ (unless otherwise noted)

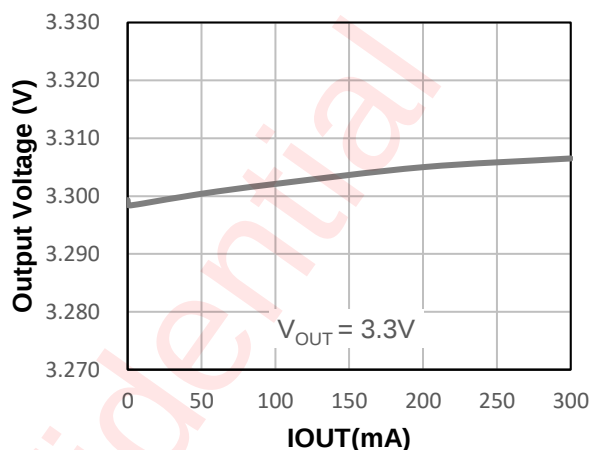
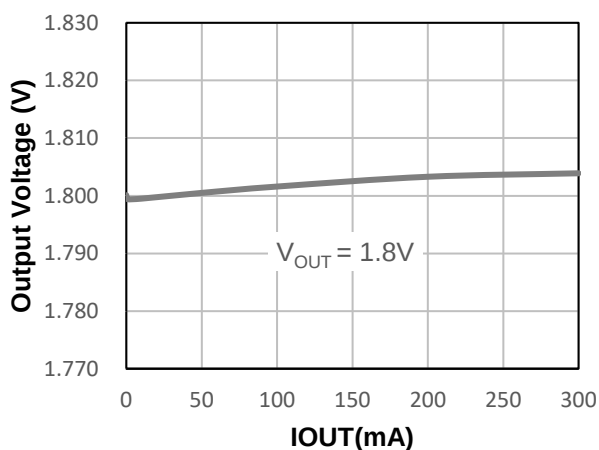
PARAMETER		TEST CONDITION	MIN	TYP	MAX	UNIT
V_{IN}	Input Voltage Range		1.2		5.5	V
V_{OUT_ACC}	Output Voltage Accuracy	$T_A=25^{\circ}C$, $I_{OUT}=1mA$	-2		2	%
$LOAD_{Reg}$	Load Regulation	$1mA \leq I_{OUT} \leq 300mA$		0.5		%
$LINE_{Reg}$	Line Regulation	$V_{OUT(SET)}+0.5V \leq V_{IN} \leq 5.5V$, $I_{OUT}=1mA$		1		mV
$V_{dropout}$	Dropout Voltage ⁽¹⁾ $I_{OUT}=300mA$	$V_{OUT(SET)}=1.8V$		320		mV
		$V_{OUT(SET)}=2.8V$		203		
		$V_{OUT(SET)}=3.0V$		187		
		$V_{OUT(SET)}=3.3V$		179		
I_{SD}	Shutdown Current	$V_{CE}<0.4V$		0.1	1	μA
I_Q	Quiescent Current	$I_{OUT}=0mA$		2	4	μA
V_{CEH}	CE Input Voltage "H"	$-40^{\circ}C \leq T_A \leq 85^{\circ}C$	1			V
V_{CEL}	CE Input Voltage "L"	$-40^{\circ}C \leq T_A \leq 85^{\circ}C$			0.4	V
PSRR	Power Supply Ripple Rejection	$I_{OUT}=30mA$, $f=1kHz$ $V_{OUT(SET)}=1.8V$		75		dB
V_N	Output Voltage Noise $I_{OUT}=30mA$ BW=10Hz to 100kHz	$V_{OUT(SET)}=1.8V$		60		μV_{rms}
		$V_{OUT(SET)}=2.8V$		80		
		$V_{OUT(SET)}=3.0V$		84		
		$V_{OUT(SET)}=3.3V$		90		
I_{CL}	Output Current Limit	$V_{OUT}=90\% \cdot V_{OUT(SET)}$	300			mA
I_{SC}	Short Current Limit	$V_{OUT}<10\% \cdot V_{OUT(SET)}$		300		mA
VTC	Output Voltage Temperature Coefficient	$-40^{\circ}C \leq T_A \leq 85^{\circ}C$		± 100		ppm/ $^{\circ}C$
R_{DISC}	Auto Discharge Resistance	$V_{IN}=4.3V$, $V_{CE}<0.4V$		80		Ω
I_{CE}	CE Pull Down Current			30		nA
T_{SDH}	Thermal Shutdown Threshold	Temperature Rising		155		$^{\circ}C$
T_{SDL}	Thermal Shutdown Reset Threshold	Temperature Falling		130		$^{\circ}C$

(1) Dropout voltage is the voltage difference between the input and the output at which the output voltage drops to 98% of its nominal value.

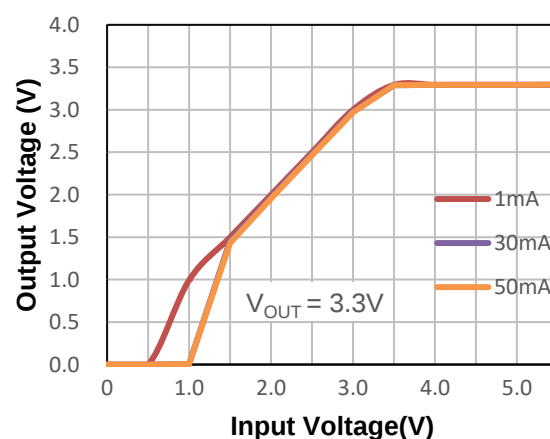
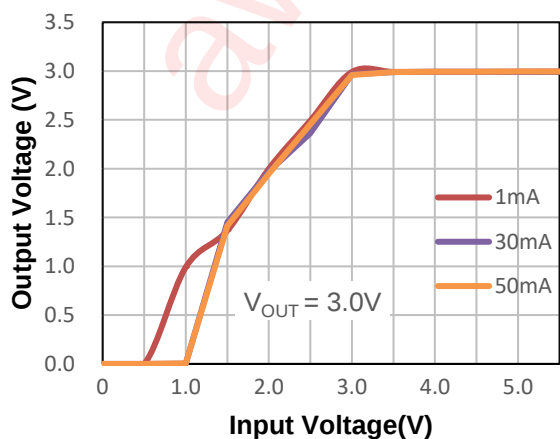
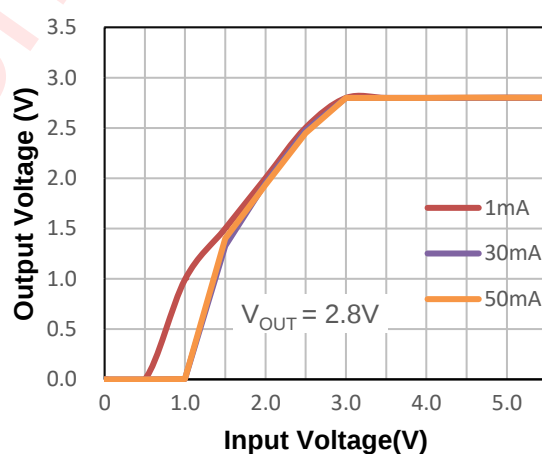
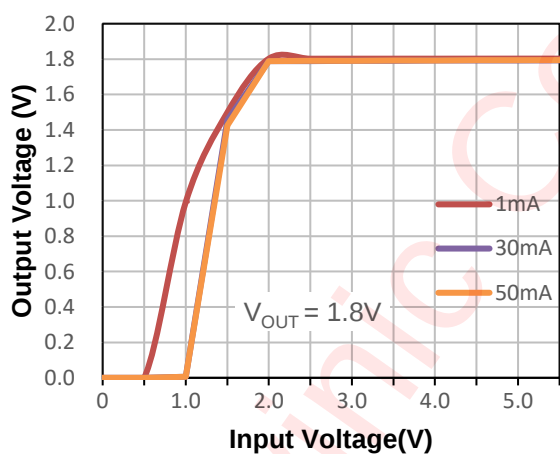
Typical Characteristics

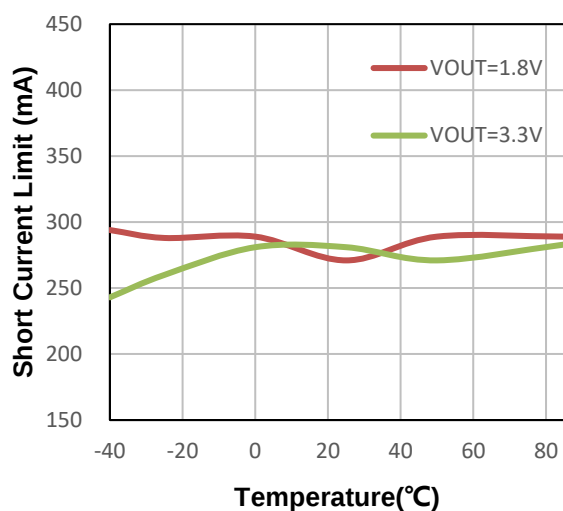
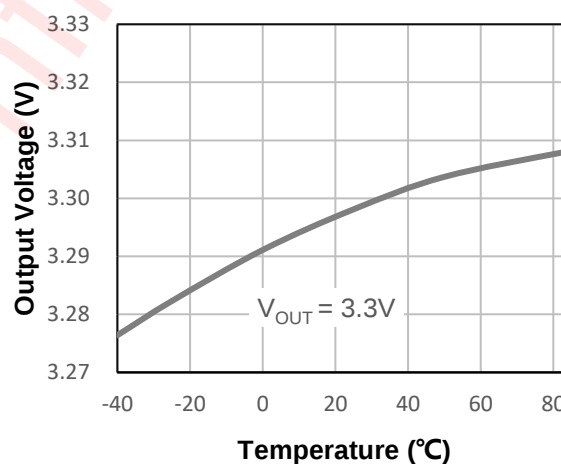
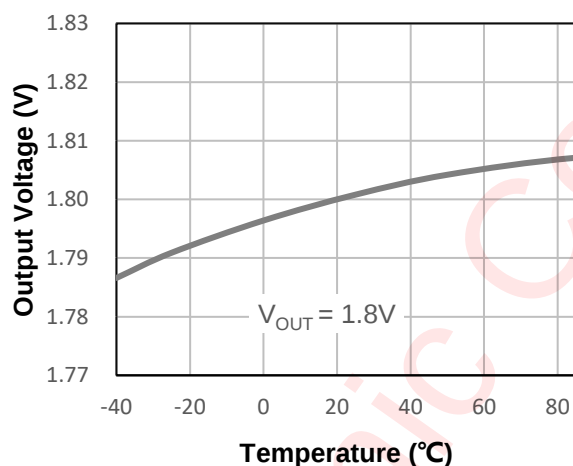
$V_{IN}=V_{OUT(SET)}+1V$, $V_{CE}>1V$, $I_{OUT}=1mA$, $C_{IN}=C_{OUT}=1\mu F$, $T_A=25^{\circ}C$, In Typical Application Circuit, unless otherwise noted.

1) Output Voltage vs. Output Current ($C_{IN}=C_{OUT}=1\mu F$, $T_A=25^{\circ}C$)

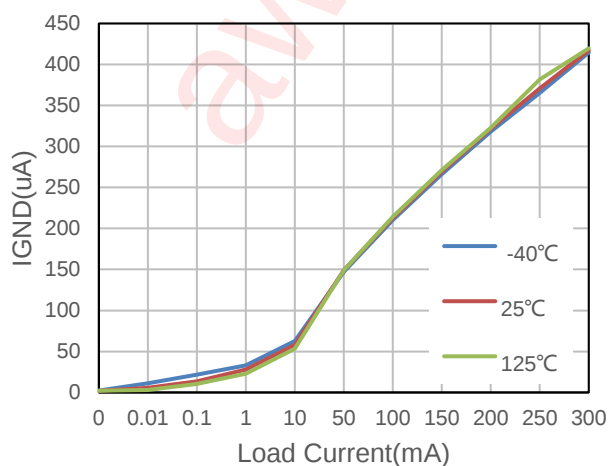


2) Output Voltage vs. Input Voltage ($C_{IN}=C_{OUT}=1\mu F$, $T_A=25^{\circ}C$)

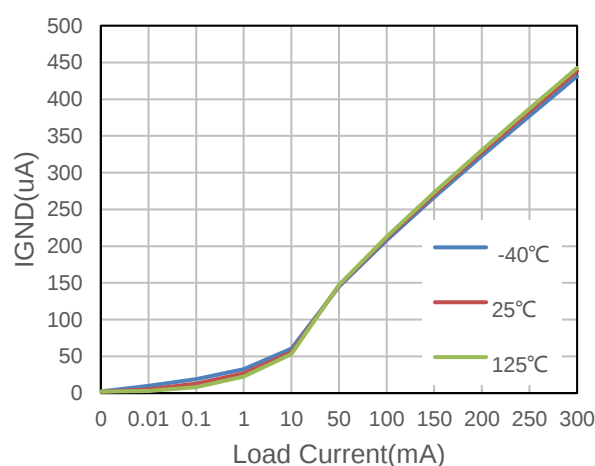


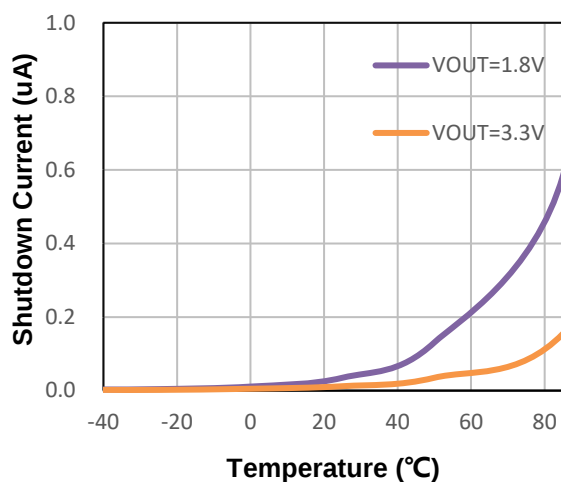
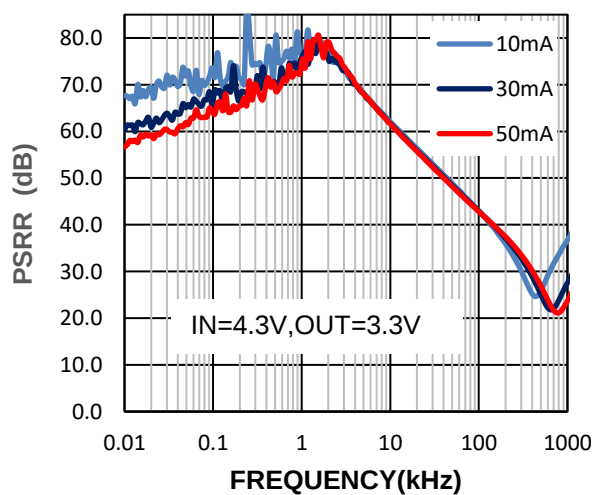
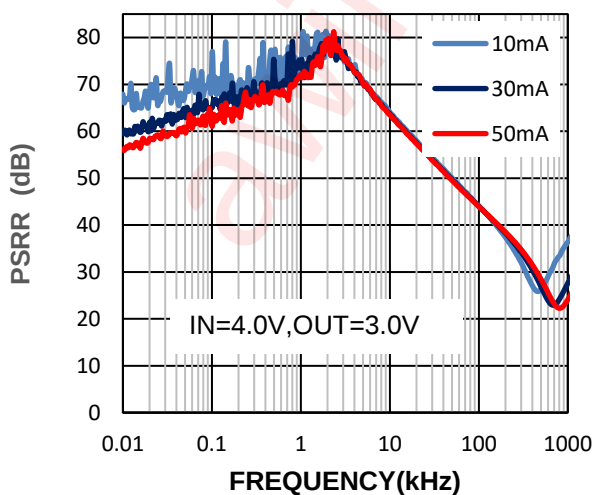
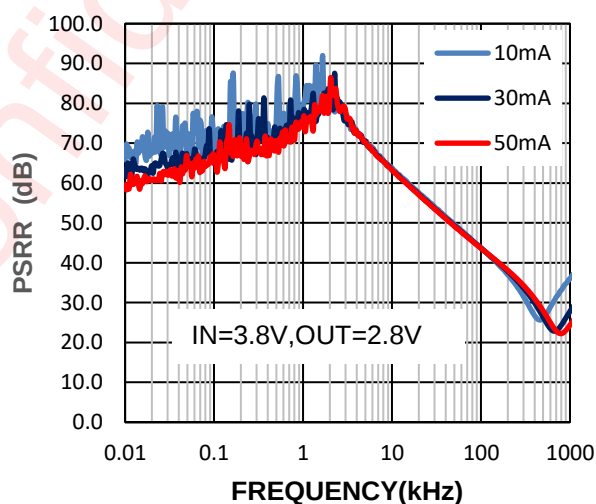
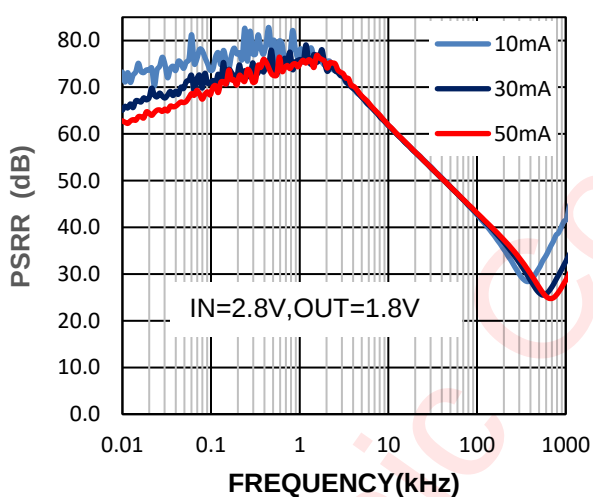
3) Short Current Limit vs. Temperature ($C_{IN}=C_{OUT}=1\mu F$)4) Output Voltage vs. Temperature ($C_{IN}=C_{OUT}=1\mu F$, $I_{OUT}=1mA$)5) Ground Current vs. Load Current ($C_{IN}=C_{OUT}=1\mu F$)

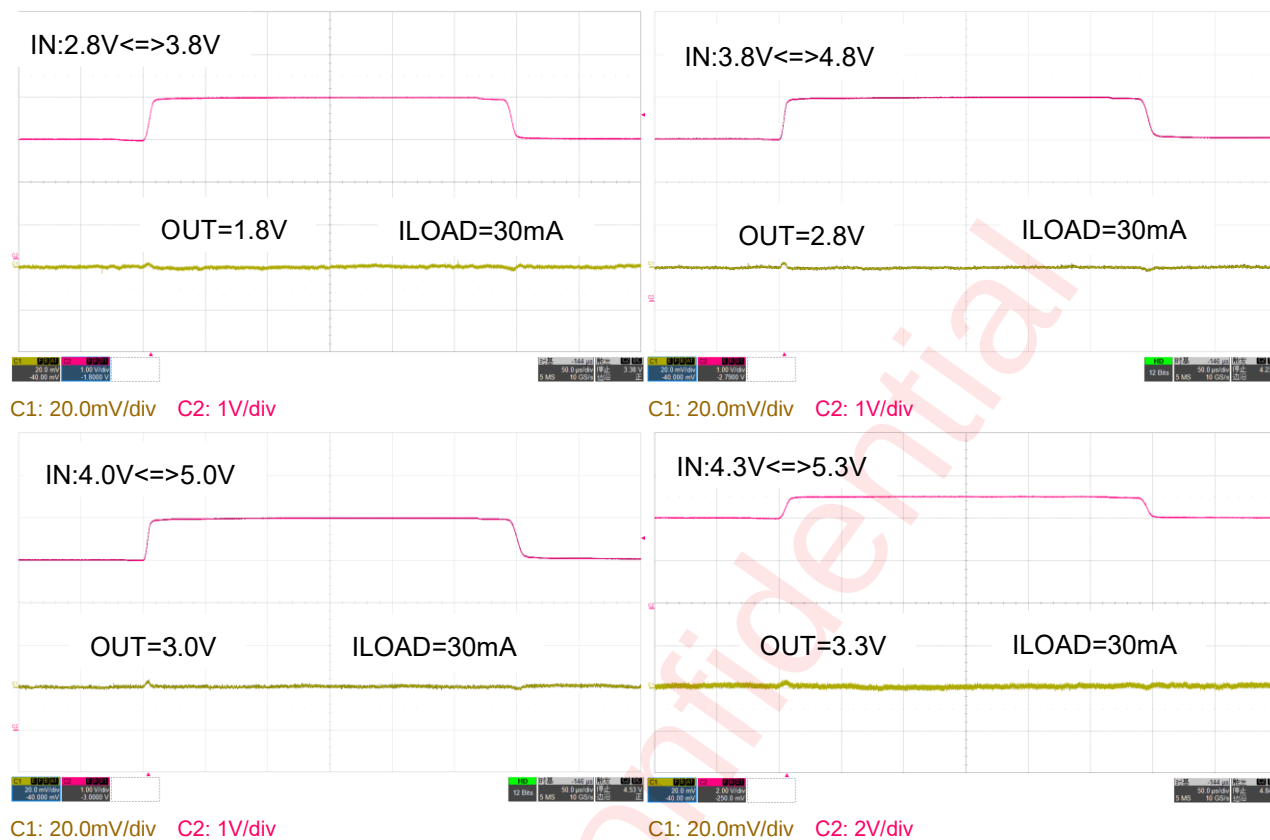
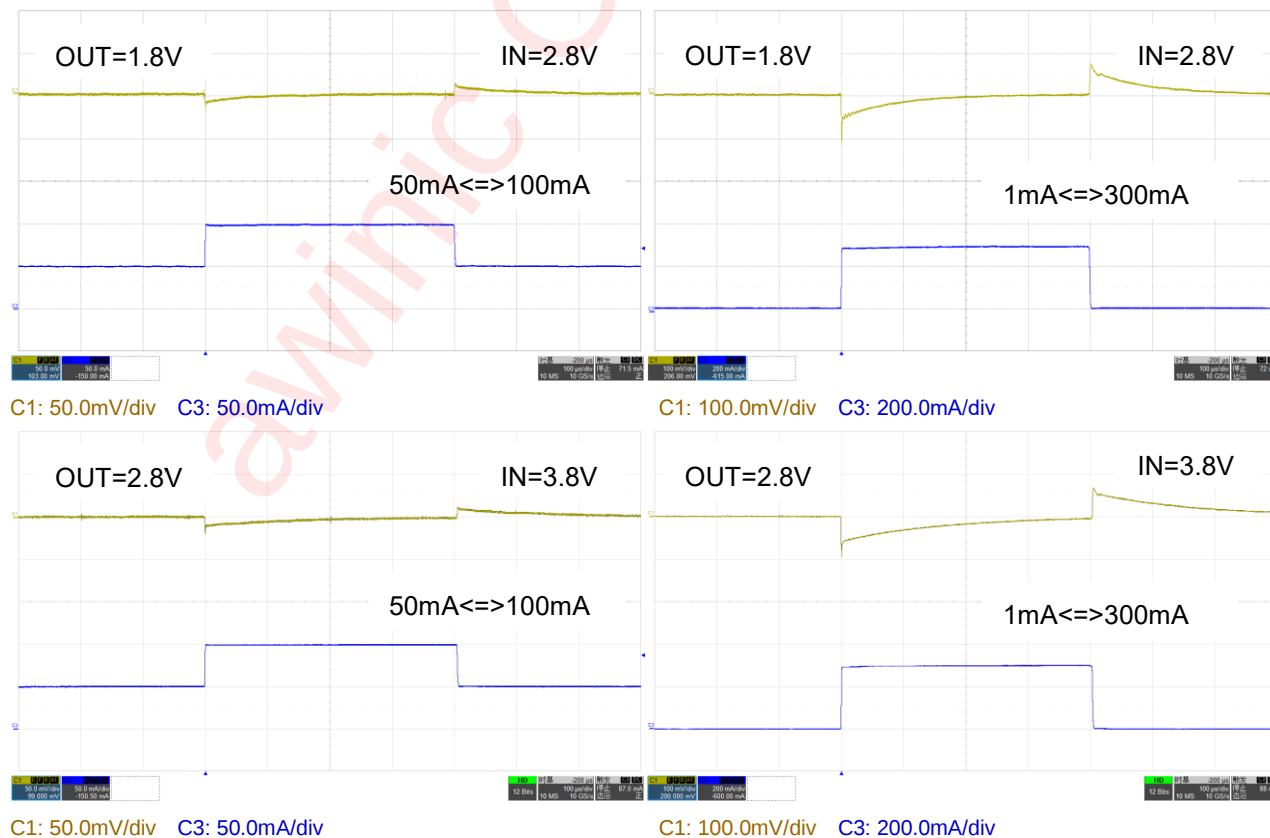
AW37103D180DNR

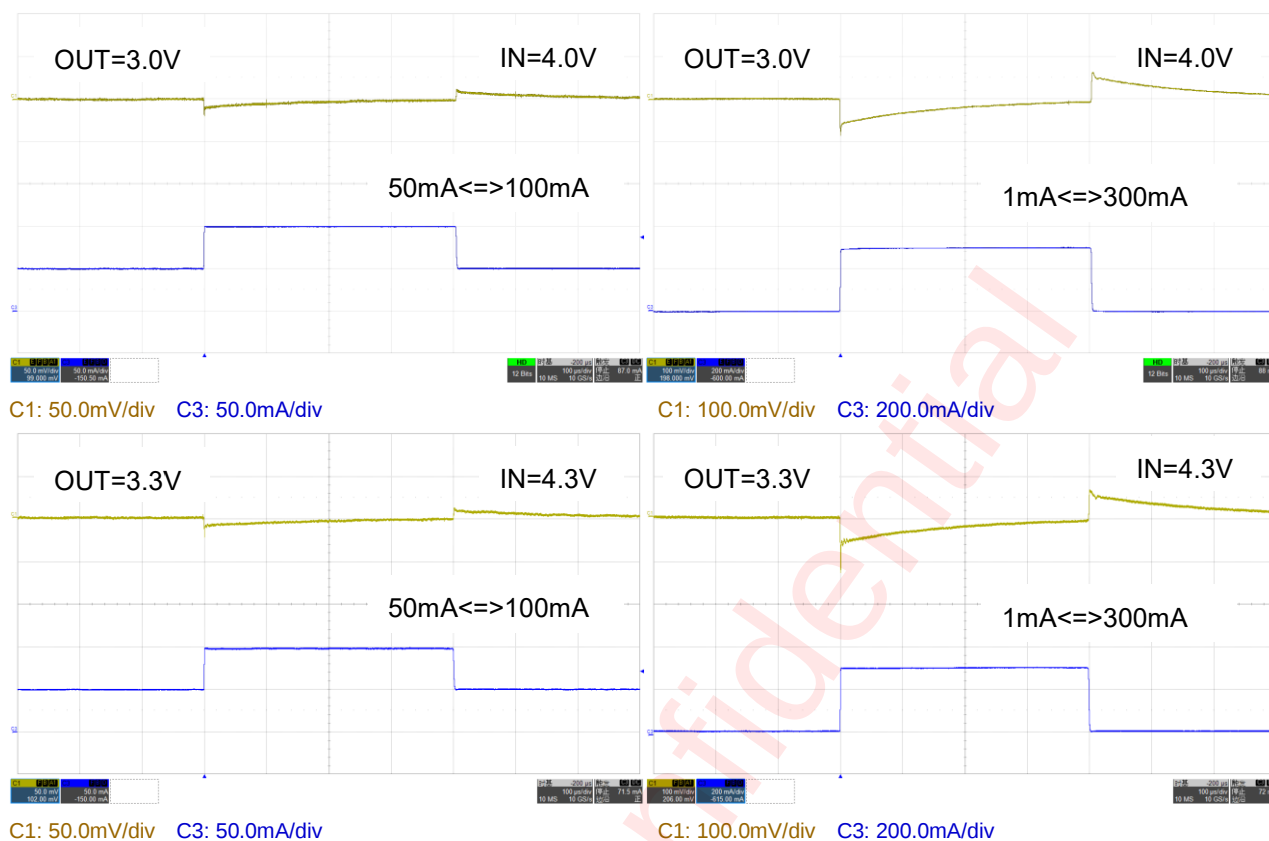


AW37103D330DNR

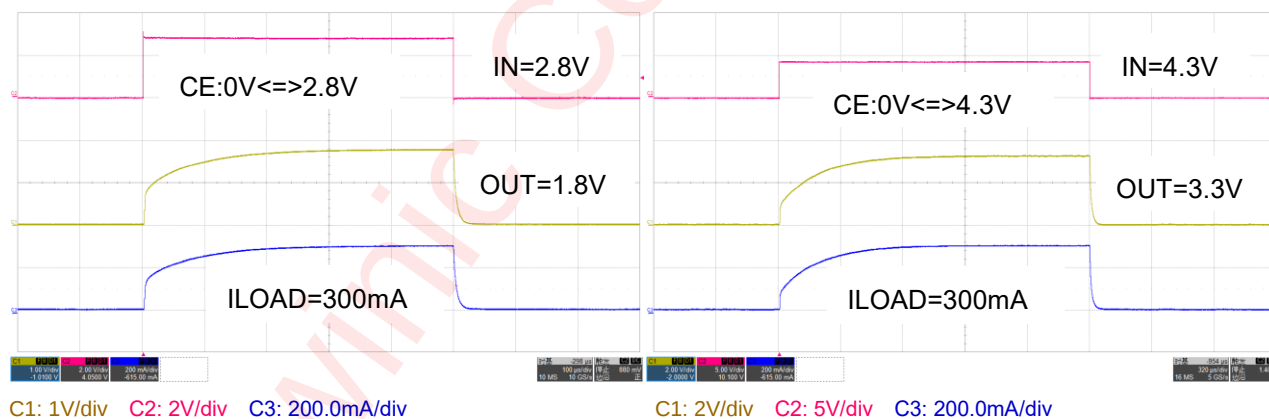


6) Shutdown Current vs. Temperature ($C_{IN}=C_{OUT}=1\mu F$)7) Ripple Rejection vs. Frequency ($C_{IN}=0.1\mu F, C_{OUT}=1\mu F, T_A=25^\circ C$)

8) Line Transient ($C_{IN}=C_{OUT}=1\mu F$, $t_r = t_f = 10\mu s$, $T_A=25^\circ C$)9) Load Transient ($C_{IN}=C_{OUT}=1\mu F$, $t_r=t_f=1\mu s$, $T_A=25^\circ C$)



10) Turn-on/off Waveform by CE Pin signal ($C_{IN}=C_{OUT}=1\mu F$, $T_A=25^\circ C$)



Detailed Functional Description

AW37104YXXX is a low quiescent current low dropout voltage regulator. After powered on, with CE pin assertion, feedback voltage signal from the integrated resistor network and a voltage related to the voltage reference are transmit to positive input terminal and negative input terminal of an error amplifier (EA) respectively. The output signal of EA is used to control the open-state of power MOSFET. After soft-start, feedback voltage signal compares with the established reference voltage, making output voltage stable and accurate. AW37104YXXX integrates function of load transient accelerating, making LDO obtain excellent dynamic load transient response performance.

Enable Operation

AW37104YXXX uses CE pin to realize enable operation. Applying proper value of voltage to CE pin can make IC enable/disable.

If the voltage of CE pin is less than 0.4V, AW37104YXXX is guaranteed to be disabled. In this state, function modules of IC and power MOSFET are turned off. And the auto discharge function is enabled making output discharge through a on-state NMOSFET to Ground. In disable state, the ground current is reduced to a maximum of 0.5uA.

If the voltage of CE pin is more than 1V, AW37104YXXX is guaranteed to be enabled. In this state, the auto discharge function is disabled, and AW37104YXXX regulates output voltage to the designed value of voltage. A 30nA pull down current to Ground is built-in at CE pin, making sure that the IC is disabled when CE pin floats. If Enable function is not required, CE pin should be connected directly to IN pin.

Output Current Limit

AW37104YXXX integrates output current limit function, protecting IC from excessive current.

When the load is excessively heavy, AW37104YXXX limits the current flowing through the IC to a typical 500mA current. This value is specially designed, so that IC is protected properly and the output capability of 300mA is not influenced either.

Meanwhile, AW37104YXXX integrates a 300mA fold-back current limit function, lowering the system dissipation when output overload or short to Ground.

Thermal Shutdown

AW37104YXXX integrates thermal shutdown function, protect IC from excessively high temperature.

When the chip temperature exceeds 155°C and the output current exceeds 50mA, AW37104YXXX detects it as an over-temperature event, triggering thermal shutdown, which will turn off the main function module, including power MOSFET. This inhibits increase of chip's temperature. IC would keep the protection-state on until the chip's temperature falls below to 130°C. At this moment, the over-temperature protection-state is released, IC resumes to work again. The hysteresis avoids IC's turning off and on frequently around the the Thermal Shutdown threshold.

Auto Discharge

AW37104YXXX makes output voltage discharge quickly when in CE disable state or thermal shutdown state, benefit from integrating auto discharge function. Auto discharge function is implemented by integrated a NMOSFET of typical 80Ω Rdson route from Output to Ground, and the route is get through in CE disable state or thermal shutdown state. This feature prevents residual charge voltage on the output capacitor, which may impact proper power up of the system connected to the converter. It should be noted that auto discharge

function is optional according to different specs.

Application Information

Power Dissipation and Device Operation

The permissible power dissipation is dependent on the ambient temperature T_A and the junction-to-ambient thermal resistance $R_{\theta JA}$.

The absolute maximum allowable power dissipation for the device in a given package can be calculated using Equation below, where $T_{J_MAX} = 150^\circ\text{C}$:

$$PD_{MAX_ABS} = (T_{J_MAX} - T_A) / R_{\theta JA}$$

The recommended maximum allowable power dissipation for the device in a given package can be calculated using Equation below, where $T_{J_REC} = 125^\circ\text{C}$:

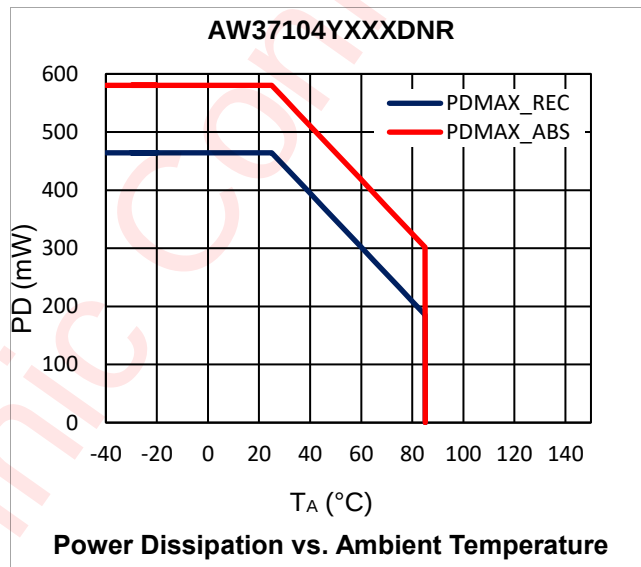
$$PD_{MAX_REC} = (T_{J_REC} - T_A) / R_{\theta JA}$$

The actual power being dissipated in the device can be represented by Equation below:

$$PD_{ACT} = (V_{IN} - V_{OUT}) \times I_{OUT}$$

These equations above establish the relationship between the maximum power dissipation allowed due to thermal consideration, the voltage drop across the device, and the continuous current capability of the device.

The graphs of Power Dissipation vs. Ambient Temperature are showed below :



The above graphs show the maximum power dissipation of the respective package at $T_{J_REC} = 125^\circ\text{C}$ and $T_{J_MAX} = 150^\circ\text{C}$. Operating the device in the region between PD_{MAX_REC} and PD_{MAX_ABS} might have a negative influence on its lifetime.

Capacitors Selection

IN pin: Input Capacitor C_{IN}

AW37104YXXX advises to use a $1\mu\text{F}$ or more X5R or X7R ceramic capacitor at IN pin as shown in Typical Application Circuit.

OUT pin: Output Capacitor C_{OUT}

AW37104YXXX advises to use a $1\mu\text{F}$ or more X5R or X7R ceramic capacitor at OUT pin as shown in Typical Application Circuit.

Recommended Components List

Component	PART No.	DESCRIPTION	MFR	TYP.	UNIT
C _{IN}	GRM155R61A105KE15	10V, X5R, 0402	MURATA	1	μF
C _{OUT}	GRM155R61A105KE15	10V, X5R, 0402	MURATA	1	μF
	GRM153R60J225ME95	6.3V, X5R, 0402	MURATA	2.2	μF
	GRM153R60J475ME15	6.3V, X5R, 0402	MURATA	4.7	μF

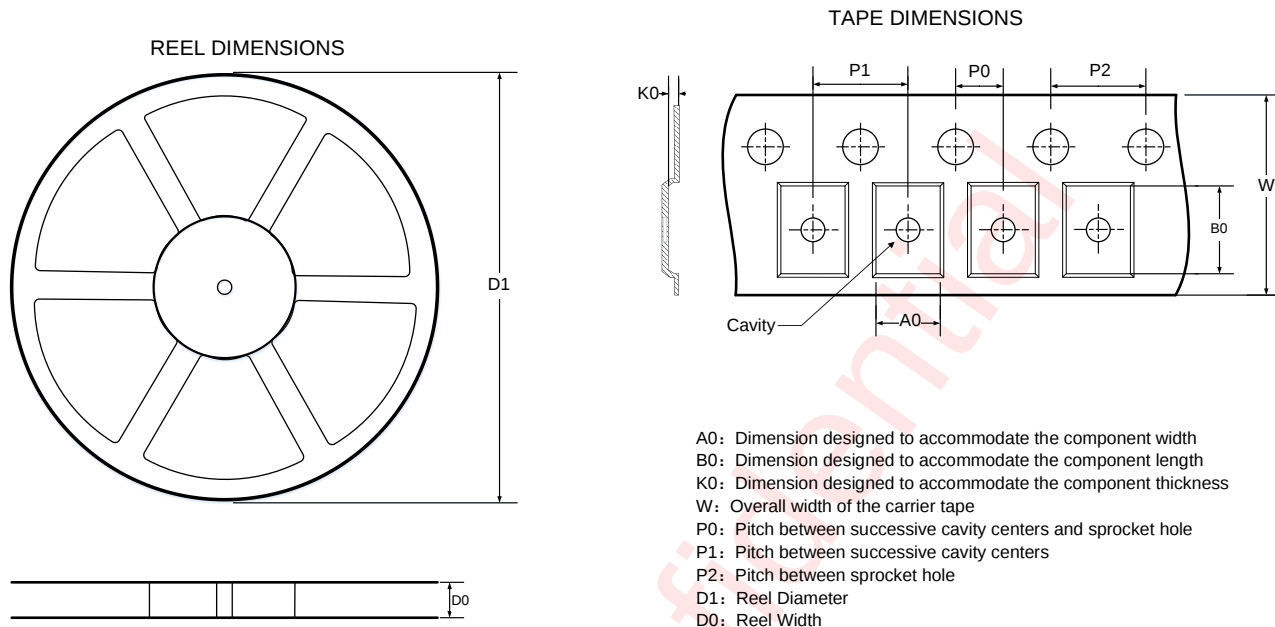
PCB Layout Consideration

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. To obtain the optimal performance, a peripheral component or the device mounted on PCB should not exceed its rated voltage, rated current or rated power. When designing a peripheral circuit, guidelines below for PCB layout of AW37104YXXX should be obeyed:

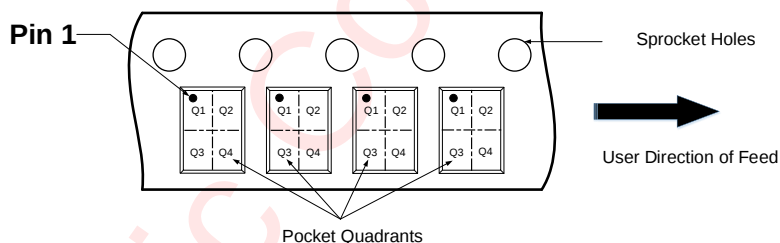
1. All peripheral components should be placed as close to the chip as possible. C_{IN} and C_{OUT} should be close to IN and OUT pins respectively. Avoid connecting device and chip pins with two different layers of copper, use the same layer of copper instead.
2. IN and OUT pin are the large current input and output of the chip, make IN, OUT, and meanwhile GND lines sufficient.
3. The connection lines between the planes of C_{IN} or C_{OUT} and respective chip pin should be as short and wide as possible, to reduce noise and EMI interference, or it may cause noise pickup or unstable operation.
4. The exposed plane of chip and GND pins must be connected to the large-area ground layer of PCB directly, meanwhile place sufficient vias below the exposed plane. Thus we can decrease the thermal resistor on the board to optimize heat-diffusion performance.

Tape And Reel Information

DFN 1mmX1mm-4L



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Note: The above picture is for reference only. Please refer to the value in the table below for the actual size

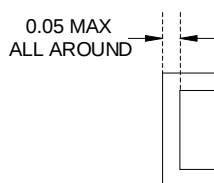
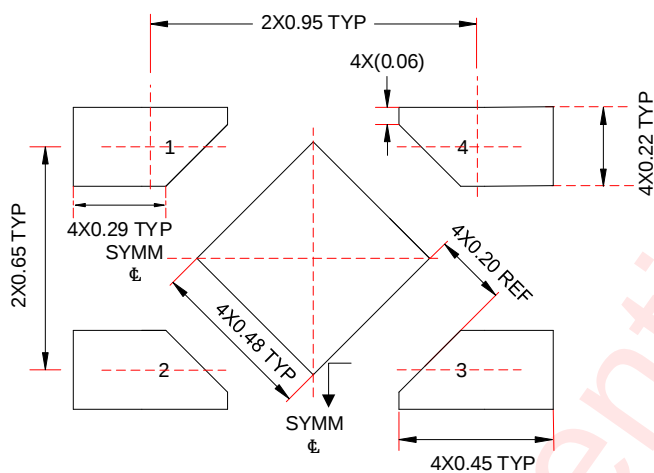
DIMENSIONS AND PIN1 ORIENTATION

D1 (mm)	D0 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
178	8.4	1.15	1.15	0.57	2	2	4	8	Q1

All dimensions are nominal

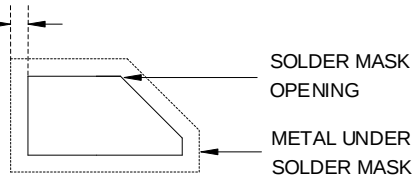
Land Pattern Data

DFN 1mmX1mm-4L



NON SOLDER MASK DEFINED

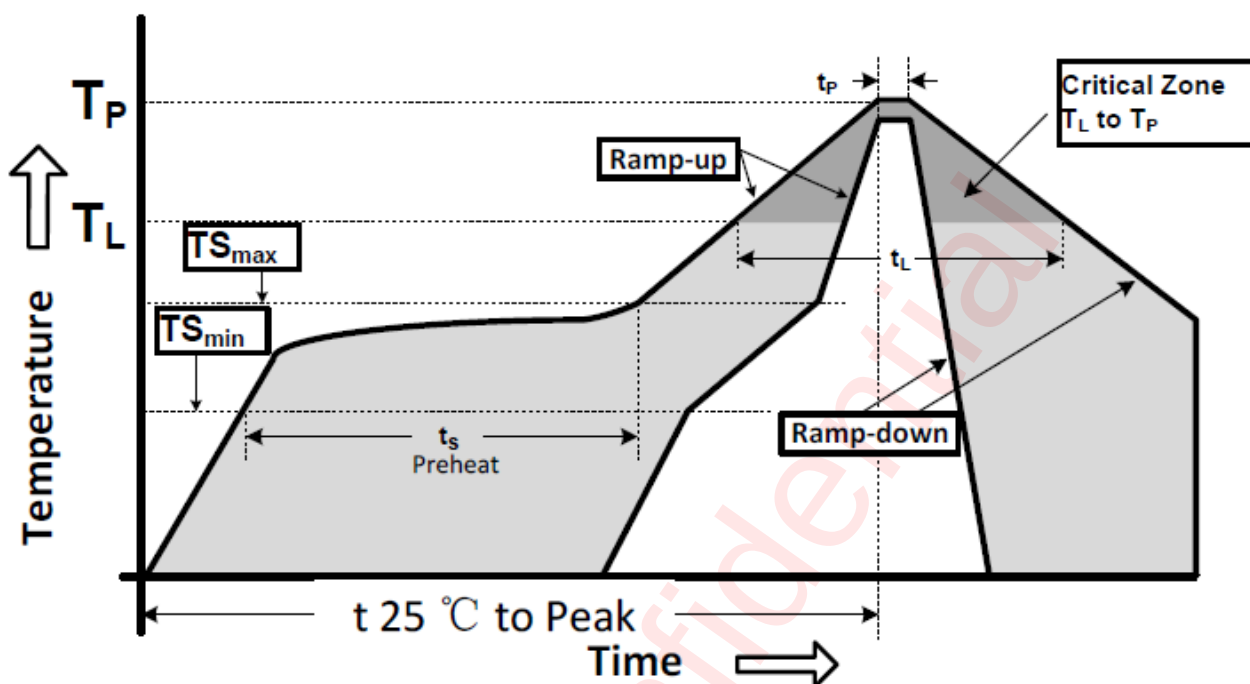
0.05 MIN
ALL AROUND



SOLDER MASK DEFINED

UNIT : mm

Reflow



Reflow Note	Spec
Ramp-up rate (TSmax to Tp)	3°C/second max.
Preheat temperature (TSmin to TSmax)	150°C to 200°C
Preheat time (ts)	60 - 180 seconds
Time above T _L , 217°C (t _L)	60 - 150 seconds
Peak temperature (Tp)	260°C
Time within 5°C of peak temperature(tp)	20 - 40 seconds
Ramp-down rate	6°C/second max.
Time 25°C to peak temperature	8 minutes max.

Revision History

Version	Date	Change Record
V1.0	Apr. 2023	Officially released
V1.1	Apr. 2023	Delivery Form change to 9000 units/Tape and Reel.

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